	Type	L #	Hits	Search Text	DBs
1	BRS	L1	114	horng near cheng.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	32	hong near liubo.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	0	tong near ru-yung.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	BRS	L4	34	tong near ru-ying.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
5	BRS	L5	23	(nicr near seed near layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	BRS	L6	5	(nicr near seed near layer) near25 (oxid$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	301	(nicr) near25 (oxid$5)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	45	(nicr) near25 (oxid$5) near25 (ta or tantalum)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
9	BRS	L9	56	(nicr) near25 (oxid$5) near25 (barrier or al)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	BRS	L10	2	(nicr) near25 (oxid$5) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
11	BRS	L11	14784	(oxid$5) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	BRS	L12	2	(nicr) near25 (ta or tantalum) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
13	BRS	L13	21	(nicr) near25 (ta or tantalum) near25 (barrier)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	BRS	L14	324	(nicr) near25 (ta or tantalum) near25 (al or aluminum)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
15	BRS	L15	0	(nicr) near25 (heat$3) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
16	BRS	L16	0	(nicr) near25 (radiat$3) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Type	L #	Hits	Search Text	DBs
17	BRS	L17	0	(nicr) near25 (irradiat$3) near25 (tunnel$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
18	BRS	L18	3281	(sputter$3) near3 (ta or tantalum)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
19	BRS	L19	6	(sputter$3) near3 (ta or tantalum) near25 (nicr)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	U	1	Document ID	Title
1			US 20040223266 A1	FeTa nano-oxide layer as a capping layer for enhancement of giant magnetoresistance in bottom spin valve structures
2			US 20030192168 A1	FeTa nano-oxide layer in pinned layer for enhancement of giant magnetoresistance in bottom spin valve structures
3			US 20030133232 A1	FeTa nano-oxide layer as a capping layer for enhancement of giant magnetoresistance in bottom spin valve structures
4			US 6773515 B2	FeTa nano-oxide layer as a capping layer for enhancement of giant magnetoresistance in bottom spin valve structures
5			US 6581272 B1	Method for forming a bottom spin valve magnetoresistive sensor element